

isc Silicon NPN Darlington Power Transistor

2SD2016

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}= 200V(Min)
- · Collector-Emitter Saturation Voltage-
 - : V_{CE(sat)}= 1.5V(Max) @I_C= 1A
- · High DC Current Gain
- : h_{FE}= 1000(Min) @ I_C= 1A, V_{CE}= 4V
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

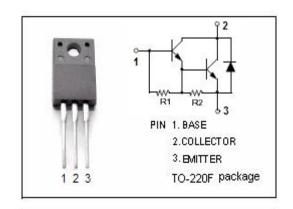


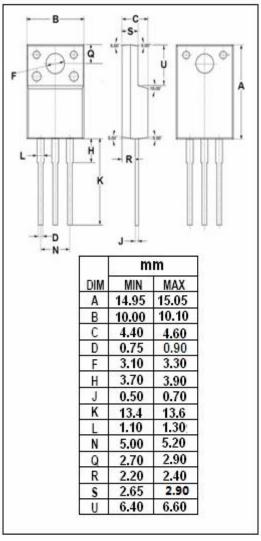
APPLICATIONS

· Igniter, relay and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	200	V
Vceo	Collector-Emitter Voltage	200	V
V _{EBO}	Emitter-Base Voltage	6	V
lc	Collector Current-Continuous	3	А
I _B	Base Current-Continuous	0.5	А
Pc	Collector Power Dissipation @ T _C =25 °C	25	W
TJ	Junction Temperature	150	$^{\circ}$ C
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$ C







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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	200			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 1A; I _B = 1.5mA			1.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 1A; I _B = 1.5mA			2.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 200V; I _E = 0			10	μА
ІЕВО	Emitter Cutoff Current	V _{EB} = 6V; I _C = 0			10	mA
h _{FE}	DC Current Gain	I _C = 1A; V _{CE} = 4V	1000		15000	
f _T	Current-Gain—Bandwidth Product	I _E = -0.1A; V _{CE} = 12V		90		MHz
Сов	Output Capacitance	V _{CB} = 10V, f _{test} = 1MHz		40		pF

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